## Abstract

First principles study of the magnetic anisotropy of Mn<sub>2</sub>Vln (001) films show perpendicular magnetic anisotropy (PMA), which increases as a function of the thickness of the film. Density functional theory (DFT) as implemented in the Vienna Ab initio simulation package (VASP) is employed here to perform a comprehensive theoretical investigation of the structural, electronic and magnetic properties of the Mn<sub>2</sub>Vln(001) films of varying thickness. Our calculations were performed on fully relaxed structures, with five to seventeen mono layers (ML). The degree of spin polarization is higher in the (001) Mn<sub>2</sub>Vln thin films as compared to the bulk in contrast to what is usually the case and as in Mn<sub>2</sub>VAI, which is isoelectronic to Mn<sub>2</sub>Vln as well as inCo<sub>2</sub>Vln (001) films studied for comparison. Tetragonal distortions are found in all the systems after relaxation. The distortion in the Mn<sub>2</sub>Vln system persists even for the 17ML thin film, resulting in PMA in the Mn<sub>2</sub>Vln system. This significant finding has potential to contribute to spin transfer torque (STT) and magnetic random access memory MRAM applications, as materials with PMA derived from volume magnetocrystalline anisotropy are being proposed as ideal magnetic electrodes